

General Description

The GreenMOS[®] high voltage MOSFET utilizes charge balance technology to achieve outstanding low on-resistance and lower gate charge. It is engineered to minimize conduction loss, provide superior switching performance and robust avalanche capability.

The GreenMOS[®] Generic series is optimized for extreme switching performance to minimize switching loss. It is tailored for high power density applications to meet the highest efficiency standards.

Features

- Low $R_{DS(ON)}$ & FOM
- Extremely low switching loss
- Excellent stability and uniformity



Applications

- PC power
- LED lighting
- Telecom power
- Server power
- EV Charger
- Solar/UPS

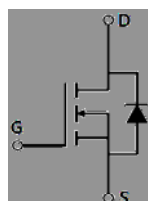
Key Performance Parameters

Parameter	Value	Unit
$V_{DS, min} @ T_{j(max)}$	650	V
$I_{D, pulse}$	9	A
$R_{DS(ON), max} @ V_{GS}=10V$	1.8	
Q_g	7.0	nC

Marking Information

Product Name	Package	Marking
OSG60R1K8AF	TO251	OSG60R1K8A

Package & Pin Information

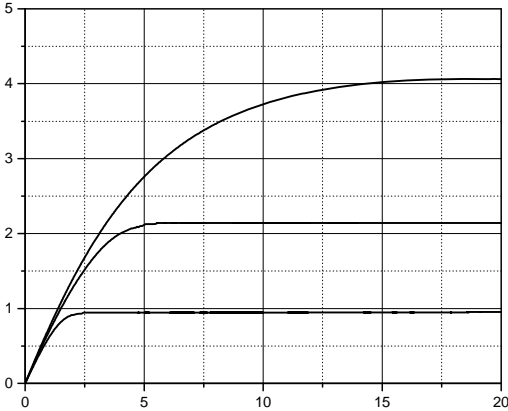


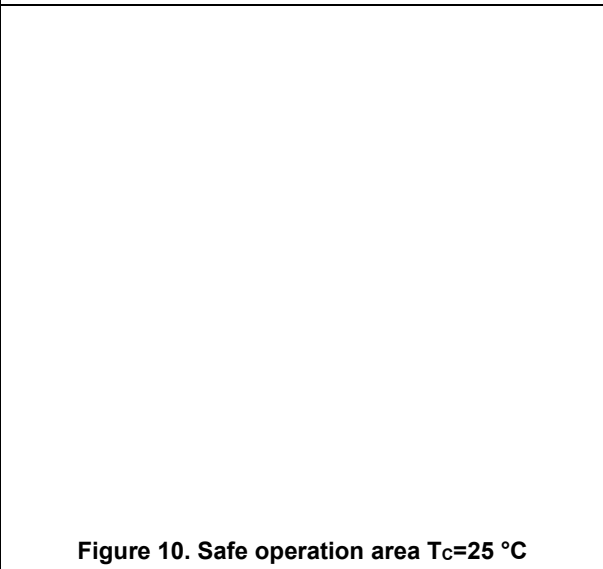
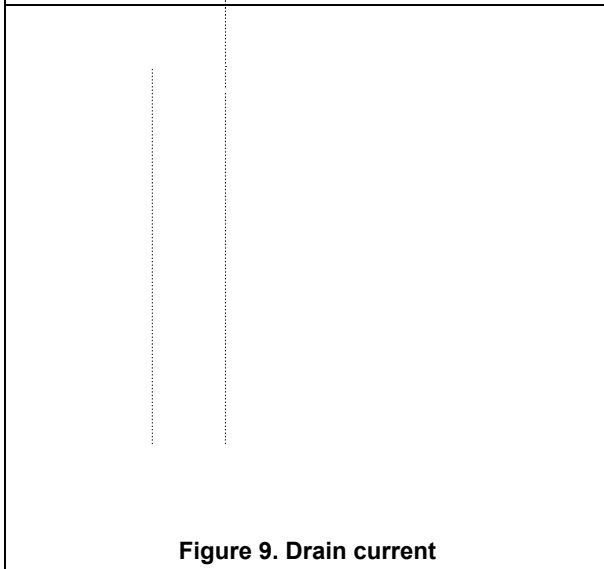
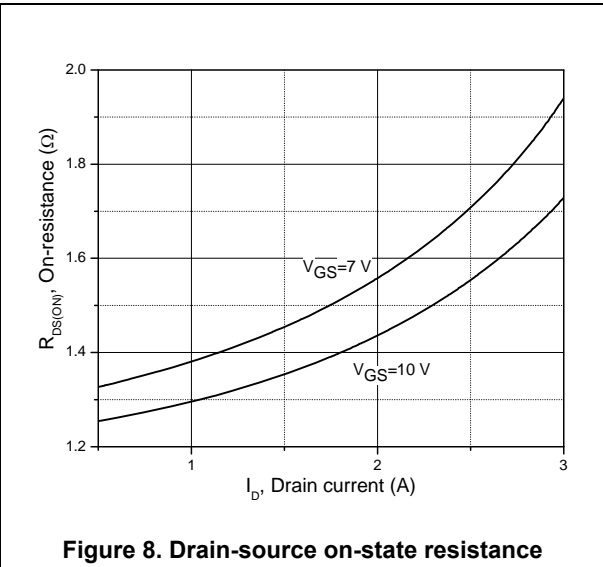
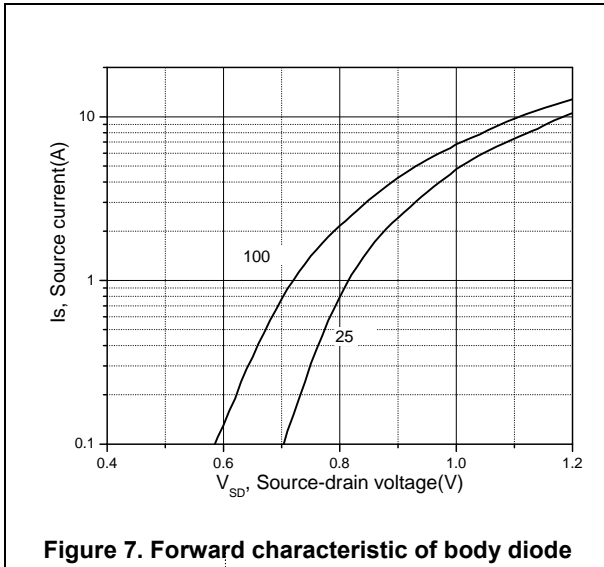
Absolute Maximum Ratings at $T_j=25^{\circ}\text{C}$ unless otherwise noted

Parameter	Symbol	Value	Unit
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Output capacitance	C_{oss}	14	pF	V _{GS} =0V, V _{DS} =50V, f=1MHz
Reverse transfer capacitance	C_{rss}	0.86	pF	
Turn-on delay time	t _{on}			

Electrical Characteristics Diagrams

 <p>Figure 1. Typ. output characteristics</p>	<p>Figure 2. Typ. transfer characteristics</p>
<p>Figure 3. Typ. capacitances</p>	<p>Figure 4. Typ. gate charge</p>
<p>Figure 5. Drain-source breakdown voltage</p>	<p>Figure 6. Drain-source on-state resistance</p>



Test circuits and waveforms

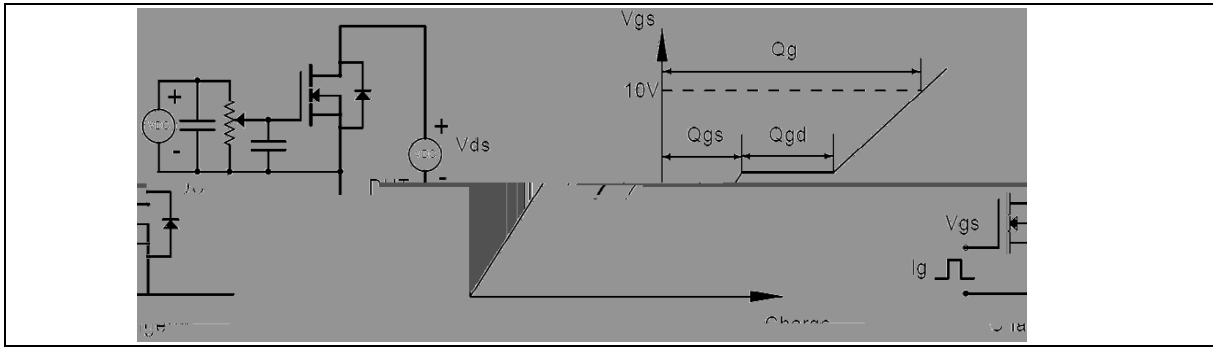


Figure 1. Gate charge test circuit & waveform

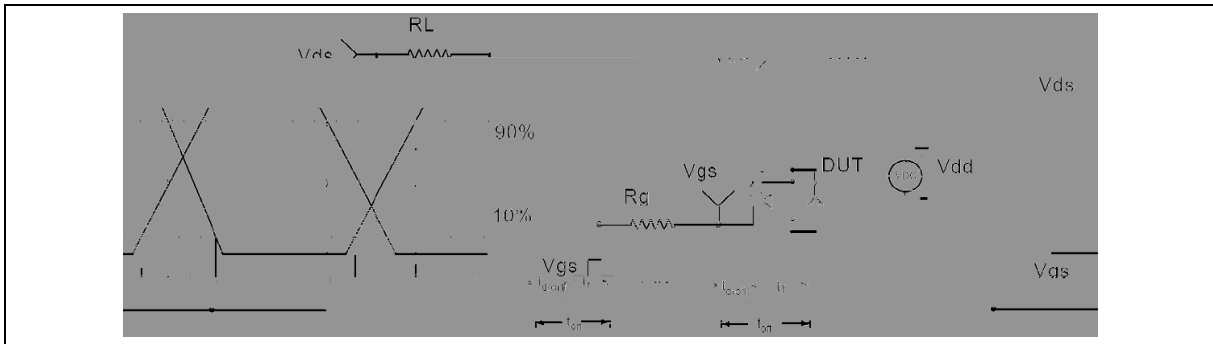


Figure 2. Switching time test circuit & waveforms

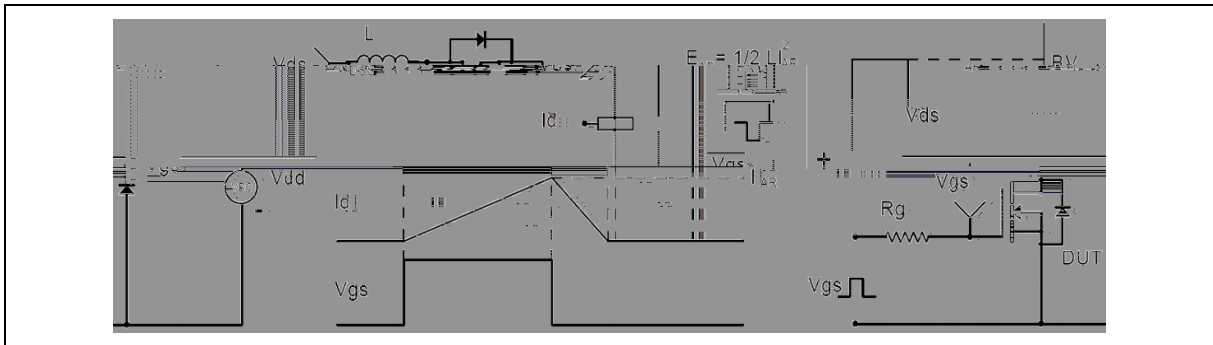


Figure 3. Unclamped inductive switching (UIS) test circuit & waveforms

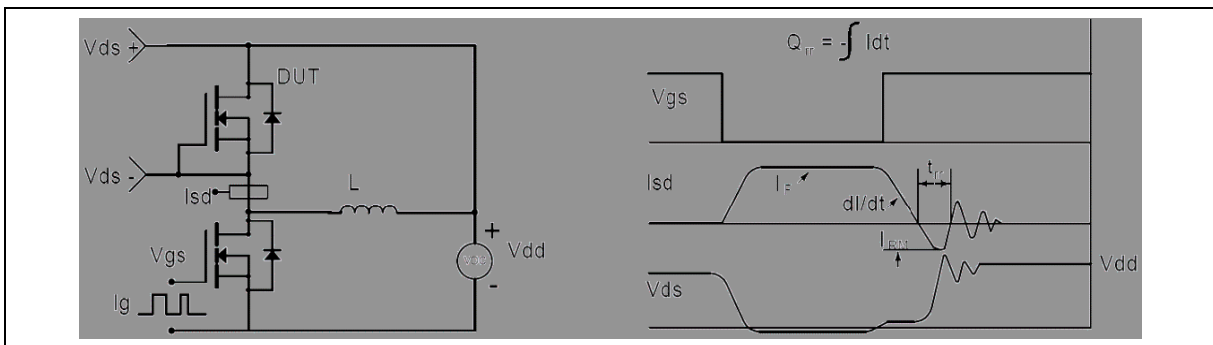
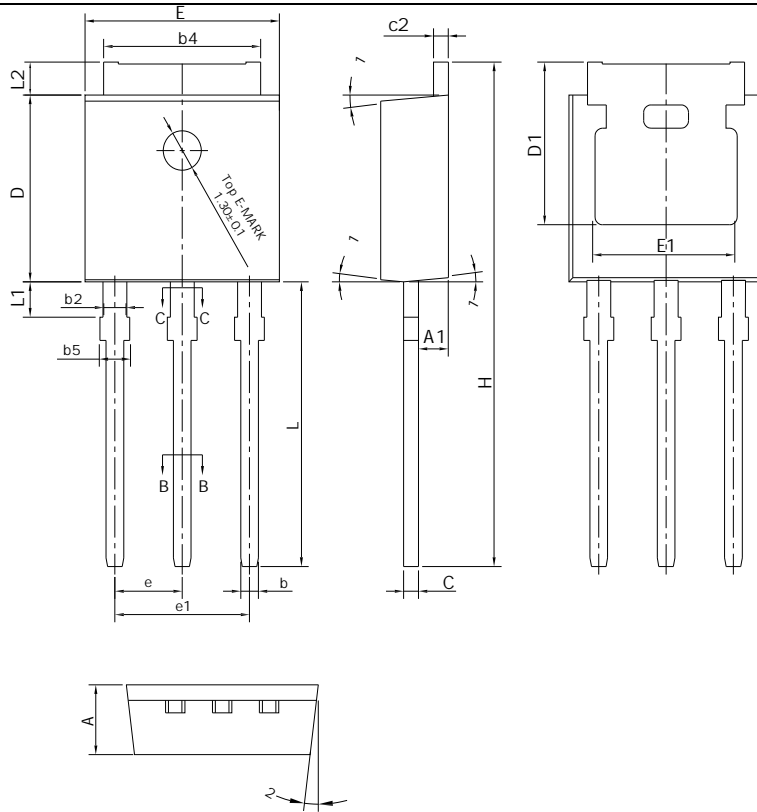


Figure 4. Diode reverse recovery test circuit & waveforms

Package Information



Symbol	mm		
	Min	Nom	Max
A	2.20	2.30	2.35
A1	0.90	1.01	1.10
b	0.56	-	0.69
b1	0.55	0.60	0.65
b2	0.77	-	0.90
b3	0.76	0.81	0.86
b4	5.23	5.33	5.43
b5	-	-	1.05
c	0.46	-	0.59
c1	0.45	0.51	0.55
c2	0.46	-	0.59
D	6.00	6.10	6.20
D1	5.20	-	-
E	6.50	6.60	6.70
E1	4.60	4.83	5.00
e	2.24	2.29	2.34
e1	4.47	4.57	4.67
H	16.18	16.48	16.78
L	9.00	9.30	9.60
L1	0.95	1.16	1.35
L2	0.90	1.08	1.25
1	3°	5°	7°
2	1°	3°	5°

Version 1: TO251-J package outline dimension

Ordering Information

Package Type	Units/ Reel	Reels / Inner Box	Units/ Inner Box	Inner Box/ Carton Box	Units/ Carton Box
TO251-J	75	60	4500	5	22500

Product Information

Product	Package	Pb Free	RoHS	Halogen Free
OSG60R1K8AF	TO251	yes	yes	yes

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